

$AZ^{\mathbb{R}}$ $nLOF^{TM}$ 5000 Photoresist

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Product Description

AZ® nLOFTM 5000 Series I-line photoresists are uniquely formulated to simplify the historically complex lift-off lithography process. You can now run a standard lithography process to get the desired lift-off profiles. The fast nLOF resists work well in both surfactant and surfactant-free TMAH developers using standard conditions.

nLOF 5000 Series resists can be used for sub 0.5μm lift-off processing.

Features Benefits

• High Throughput i-line DTP ~ 100mJ/cm²

Streamlined Lift-Off
 Process
 Standard single-layer
 lithography process to achieve lift-off profiles.

No extra steps required!!

Process Compatibility Easy integration with an existing process with

standard process conditions!

beyond 0.5µm with no process enhancements!

Standard Process Conditions

Coat: 1.0 µm resist thickness

Softbake: 90°C for 60 sec

Exposure: Nikon Stepper @ NA=0.54

 $DTP = 144 \text{ mJ/cm}^2$

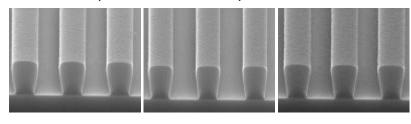
PEB: 110°C for 60sec

Develop: AZ® 300MIF Developer for

60 sec single puddle @

23°C

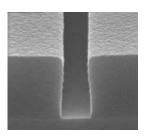
Depth of Focus @ 0.7 µm Dense Lines



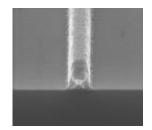
F = -0.9 F = 0.0

F = 0.6

Metal Lift-off Process Results Resist Trench Metal Isolated Line

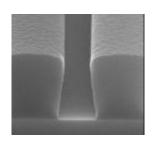


 $0.40 \, \mu m$

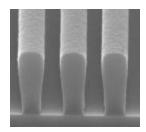


 $0.40 \mu m$

Resolution Capabilities Isolated Trench Dense Lines



0.38 µm



 $0.38 \, \mu m$





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Storage

Keep in sealed original containers away from oxidants, sparks, and open flame. Protect from light and heat. Keep refrigerated. Recommended storage temperature of 45°F. Empty container may contain harmful residue and/or vapors. Dispose of appropriately.

Equipment Compatibility

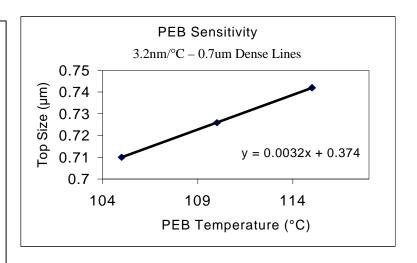
AZ nLOF 5000 Series resists are compatible with all commercially available wafer and photomask processing equipment. Recommended materials of construction include stainless steel, glass, ceramic, PTFE, polypropylene, and HDPE.

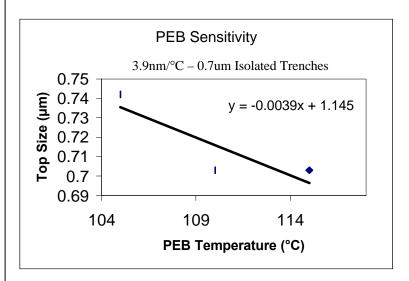
Solvent Safety

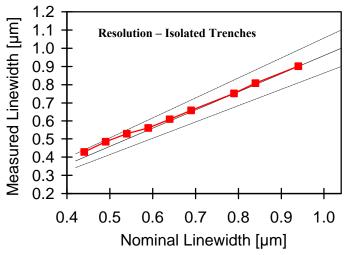
AZ nLOF 5000 Series resists are formulated with 100% PGMEA, a safer solvent. We recommend AZ EBR 70/30 as a compatible solvent for EBR processing, resist cleaning, basic resist stripping and re-work. AZ 300T, AZ 400T, or AZ Kwik Strip™ are recommended for typical resist stripping processes.

Handling Precautions / First Aid

Refer to current Material Safety Data Sheet (MSDS) for detailed information prior to handling.









Contact your local **Clariant-AZ Electronic Materials** Representative for further information at the following locations: Somerville, NJ: 800.515.4164

Dallas, TX: 800.422.3884 San Jose, CA: 408.616.2100